

Bipolar Transistor

(-)50 V, (-)3 A, Low V_{CE(sat)}, (PNP) NPN Single PCP

2SA2125, 2SC5964

Features

- Adoption of MBIT Processes
- Low Collector to Emitter Saturation Voltage
- Large Current Capacity
- High-Speed Switching
- Halogen Free Compliance

Applications

 DC-DC Converter, Relay Drivers, Lamp Drivers, Motor Drivers, Flash

Specifications

(): 2SA2125

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

| Symbol | Parameter | Conditions | Ratings | Unit |
|------------------|---------------------------------|---|----------------|------|
| V _{CBO} | Collector to Base Voltage | - | (-50)100 | ٧ |
| V _{CES} | Collector to Emitter Voltage | Т | (-50)100 | V |
| V _{CEO} | Collector to Emitter Voltage | I | (–)50 | ٧ |
| V _{EBO} | Emitter to Base Voltage | - | (–)6 | ٧ |
| I _C | Collector Current | - | (–)3 | Α |
| I _{CP} | Collector Current (Pulse) | - | (-)6 | Α |
| Ι _Β | Base Current | - | (-)600 | mA |
| P _C | Collector Dissipation | When mounted on ceramic substrate (250 mm ² x 0.8 mm) | 1.3 | W |
| | | T _C = 25°C | 3.5 | W |
| Tj | Junction Temperature | - | 150 | °C |
| Tstg | Storage Temperature | - | –55 to +150 | °C |

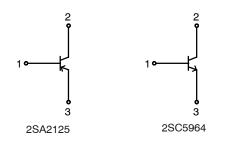
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



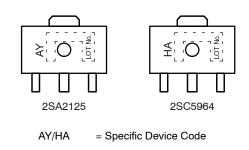
- 1. Base
- 2. Collector
- Emitter

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ELECTRICAL CONNECTIONS



MARKING DIAGRAMS



ORDERING INFORMATION

See detailed ordering and shipping information on page 6 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_A = 25°C)

| Symbol | Parameter | Conditions | Ratings | | Unit | |
|------------------------|---|---|----------|-----------|-----------|-----|
| | | | Min | Тур | Max | 1 |
| I _{CBO} | Collector Cutoff Current | V _{CB} = (-)40 V, I _E = 0 A | - | _ | (-)1 | μΑ |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = (-)4 V, I _C = 0 A | _ | _ | (-)1 | μΑ |
| h _{FE} 1 | DC Current Gain | V _{CE} = (-)2 V, I _C = (-)100 mA | 200 | _ | 560 | |
| f _T | Gain-Bandwidth Product | V _{CE} = (-)10 V, I _C = (-)500 mA | _ | (390)380 | - | MHz |
| Cob | Output Capacitance | V _{CB} = (-)10 V, f = 1 MHz | - | (24)13 | _ | pF |
| V _{CE(sat)} 1 | Collector to Emitter Saturation Voltage | I _C = (-)1 A, I _B = (-)50 mA | _ | (-125)100 | (-230)150 | mV |
| V _{CE(sat)} 2 | | I _C = (-)2 A, I _B = (-)100 mA | _ | (-250)190 | (-500)290 | mV |
| V _{BE(sat)} | Base to Emitter Saturation Voltage | I _C = (-)2 A, I _B = (-)100 mA | _ | (-)0.94 | (-)1.2 | V |
| V _{(BR)CBO} | Collector to Base Breakdown Voltage | $I_C = (-)10 \mu A, I_E = 0 A$ | (-50)100 | _ | - | V |
| V _{(BR)CES} | Collector to Emitter Breakdown Voltage | I_C = (-)100 μA, R_{BE} = 0 Ω | (-50)100 | _ | - | V |
| V _{(BR)CEO} | | I _C = (-)1 mA, R _{BE} = ∞ | (–)50 | _ | - | V |
| V _{(BR)EBO} | Emitter to Base Breakdown Voltage | I _E = (-)10 μA, I _C = 0 A | (–)6 | _ | - | V |
| t _{on} | Turn-ON Time | See specified Test Circuit | - | (30)35 | - | ns |
| t _{stg} | Storage Time | 1 | - | (230)300 | - | ns |
| t _f | Fall Time | 1 | _ | (18)25 | - | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

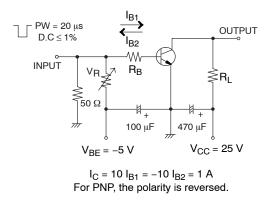
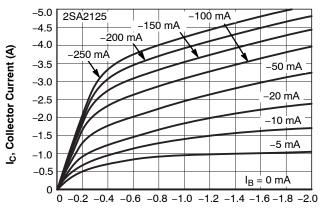


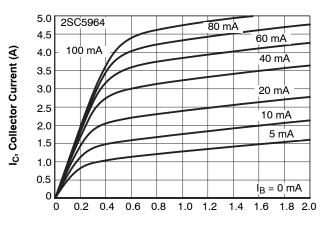
Figure 1. Switching Time Test Circuit

TYPICAL CHARACTERISTICS



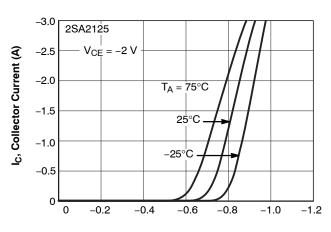
V_{CE}, Collector to Emitter Voltage (V)

Figure 2. I_C - V_{CE}



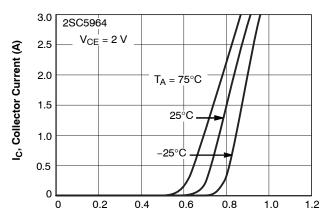
 V_{CE} , Collector to Emitter Voltage (V)

Figure 3. I_C - V_{CE}



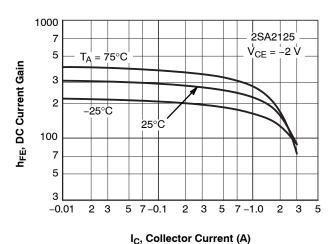
V_{BE}, Base to Emitter Voltage (V)

Figure 4. I_C - V_{BE}



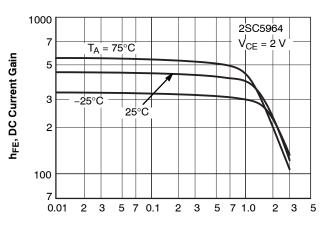
V_{BE}, Base to Emitter Voltage (V)

Figure 5. I_C - V_{BE}



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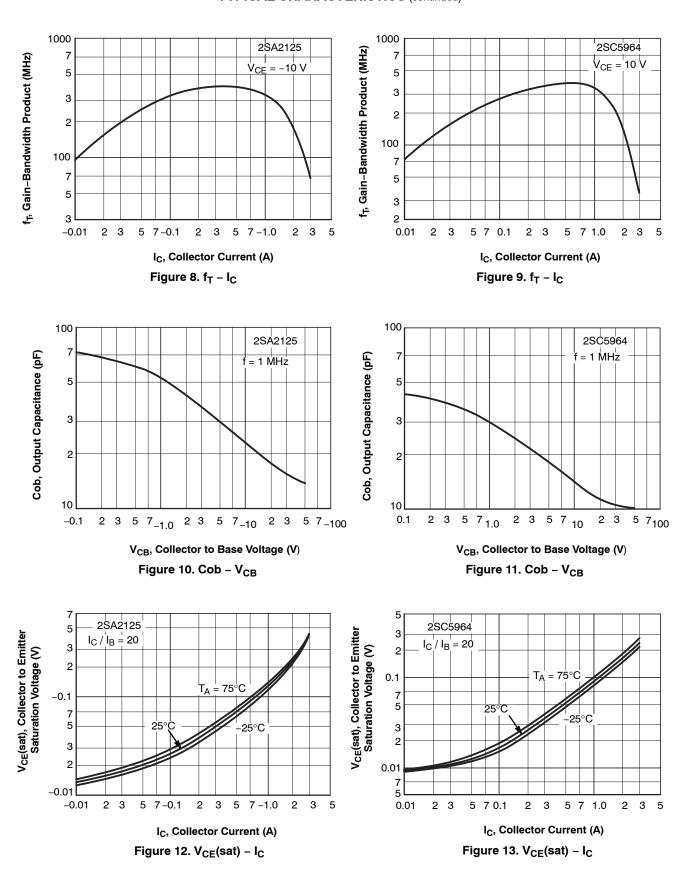
Figure 6. h_{FE} - I_C



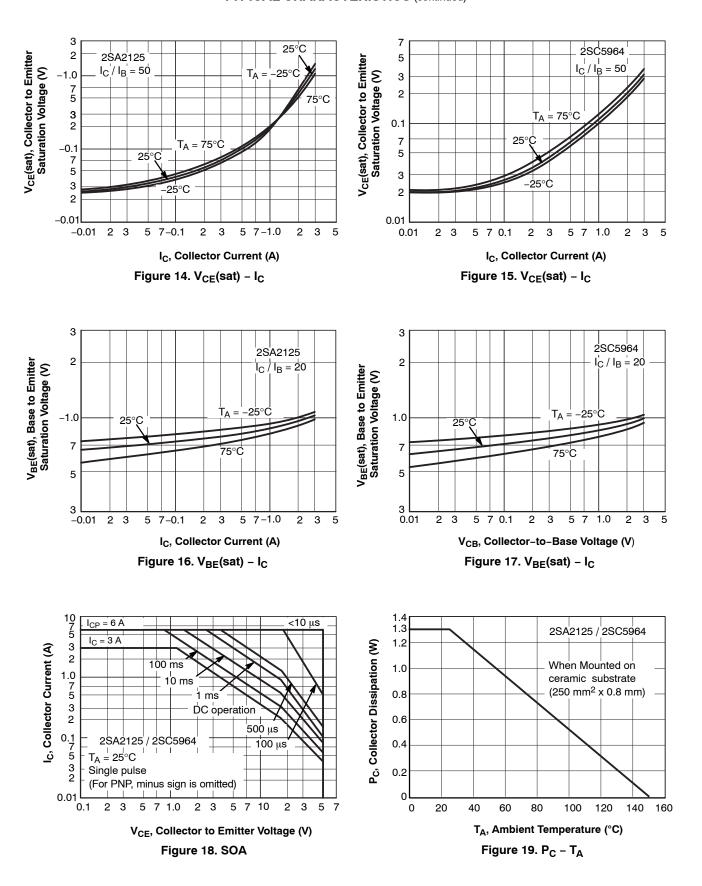
I_C, Collector Current (A)

Figure 7. h_{FE} - I_C

TYPICAL CHARACTERISTICS (continued)



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TYPICAL CHARACTERISTICS (continued)

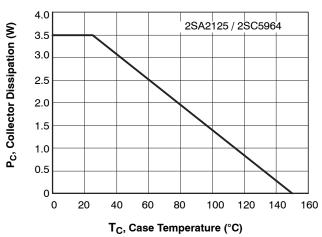


Figure 20. P_C – T_C

ORDERING INFORMATION

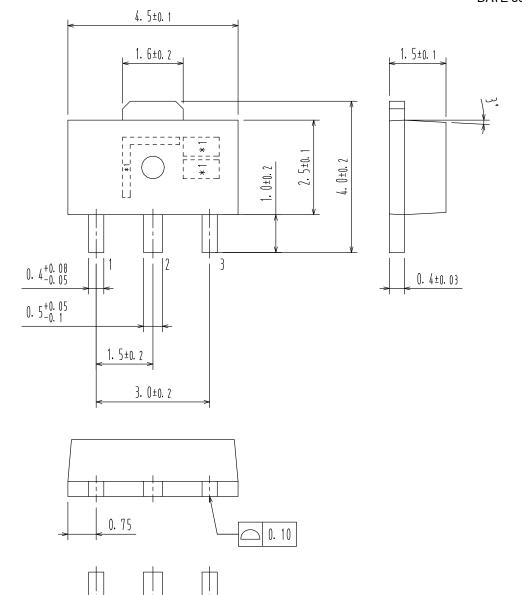
| Device | Package | Shipping [†] |
|--------------|--|-----------------------|
| 2SA2125-TD-E | SOT-89 / PCP-1 (Pb-Free) | 1000 / Tape & Reel |
| 2SA2125-TD-H | SOT-89 / PCP-1 (Pb-Free & Halogen Free) | 1000 / Tape & Reel |
| 2SC5964-TD-E | SOT-89 / PCP-1 (Pb-Free) | 1000 / Tape & Reel |
| 2SC5964-TD-H | SOT-89 / PCP-1 (Pb-Free & Halogen Free) | 1000 / Tape & Reel |

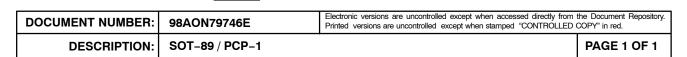
[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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DATE 30 APR 2012





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